

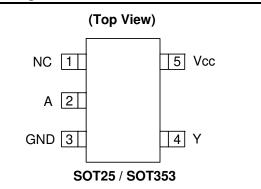
SINGLE INVERTER GATE

Description

The 74AHC1G04 is a single inverter gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

$$Y = \overline{A}$$





Features

- Supply Voltage Range from 2.0V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at Input Makes the Circuit Tolerant for Slower Input Rise and Fall Time
- ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - $\circ~$ Computer peripherals, hard drives, CD/DVD ROM
 - $\circ~$ TV, DVD, DVR, set top box
 - o Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

Ζ

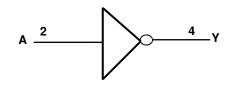


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Pin Descriptions

Pin Name	Pin NO.	Description			
NC	1	No Connection			
A	2	Data Input			
GND	3	Ground			
Y	4	Data Output			
V _{CC}	5	Supply Voltage			

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н



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Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI<0	-20	mA
I _{OK}	Output Clamp Current (V _O < 0 or V _O > V _{CC})	±20	mA
Ι _Ο	Continuous output current ($V_O = 0$ to V_{CC})	±25	mA
I _{CC}	Continuous current through V _{CC}	50	mA
I _{GND}	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol		Parameter	Min	Мах	Unit
V_{CC}	Operating Voltage		2	5.5	V
		$V_{CC} = 2V$	1.5		
VIH	High-level Input Voltage	$V_{CC} = 3V$	2.1		V
		$V_{CC} = 5.5V$	3.85		
		$V_{CC} = 2V$		0.5	
VIL	Low-level input voltage	$V_{CC} = 3V$		0.9	V
		$V_{CC} = 5.5V$		1.65	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		$V_{CC} = 2V$		-50	uA
I _{OH}	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-4	mA
		$V_{CC} = 5V \pm 0.5V$		-8	ША
		$V_{CC} = 2V$		50	uA
I _{OL}	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4	mA
		$V_{CC} = 3V$		8	MA
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	ns/V
	rate	$V_{CC} = 5V \pm 0.5V$		20	115/ V
T _A	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at $V_{\mbox{\scriptsize CC}}$ or Ground.



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Electrical Characteristics

	D	Table	N N		25ºC		-40ºC t	o 85ºC	-40ºC t	o 125ºC		
Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Min	Max	Unit	
				2V	1.9	2		1.9		1.9		
		I _{OH} = -50μA	3V	2.9	3		2.9		2.9			
V _{OH}	High Level		4.5V	4.4	4.5		4.4		4.4		V	
_	Output Voltage	$I_{OH} = -4mA$	3V	2.58			2.48		2.40			
		I _{OH} = -8mA	4.5V	3.94			3.8		3.70			
			2V			0.1		0.1		0.1		
		I _{OL} = 50μA	3V			0.1		0.1		0.1		
V _{OL}	Low Level $4.5V$ Output Voltage $I_{OL} = 4mA$ $3V$			4.5V			0.1		0.1		0.1	V
				0.36		0.44		0.55				
		I _{OL} = 8mA	4.5V			0.36		0.44		0.55		
lı	Input Current	$V_1 = 5.5 V \text{ or GND}$	0 to 5.5V			± 0.1		± 1		±2	μA	
I _{CC}	Supply Current	V _I = 5.5V or GND I _O =0	5.5V			1		10		40	μA	
CI	Input Capacitance	$V_{I} = V_{CC} - or GND$	5.5V		2.0	10		10		10	pF	
0	Thermal Resistance	SOT25	(Nata 4)		195						°C/W	
θ_{JA}	Junction-to- Ambient	SOT353	(Note 4)		430						C/W	
θ _{JC}	Thermal Resistance	SOT25 58 58		°C/W								
OJC	Junction-to- Case	SOT353	(11018 4)		155						0/00	

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

Switching Characteristics

V_{CC} = 3.3 V ± 0.3 (see Figure 1)

Deremeter	From	то			25ºC		-40ºC t	o 85ºC	-40ºC to	o 125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
+	^	V	$C_L=15pF$	0.6	4.3	7.1	0.6	8.5	0.6	11.0	ns
۱pd	A	ř	C _L =50pF	0.6	6.1	10.6	0.6	12.0	0.6	14.5	ns

V_{CC} = 5 V ± 0.5V (see Figure 1)

Peremeter	From	то			25ºC		-40ºC t	o 85ºC	-40ºC to	o 125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
+ .	^	V	$C_L=15pF$	0.6	3.1	5.5	0.6	6.5	0.6	7.0	ns
۲pd	А	ř	C _L =50pF	0.6	4.5	7.5	0.6	8.5	0.6	9.5	ns



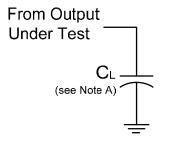
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Operating Characteristics

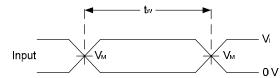
$T_A = 25 \ ^{o}C$

Parameter		Test Conditions	V _{CC} = 5V Typ.	Unit
C _{pd}	Power dissipation capacitance	f = 1 MHz No Load	12	pF

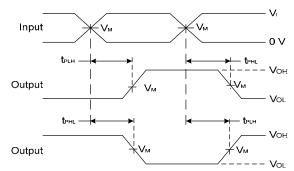
Parameter Measurement Information



V _{CC}	Inj	outs	V _M	CL
•00	VI	t _r /t _f	• 141	υĽ
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	15pF
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	15pF
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	50pF
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	50pF







Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{PD.}



Ordering Information

74AHC1G04

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Packing

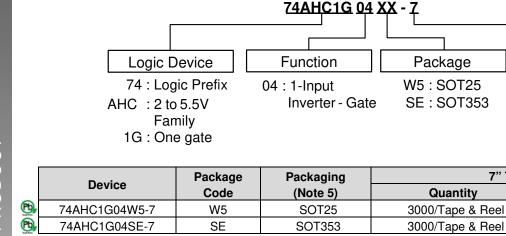
7" Tape and Reel

7 : Tape & Reel

Part Number Suffix

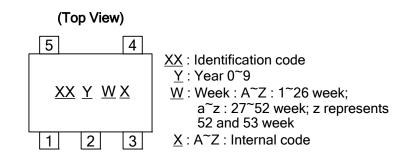
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Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information



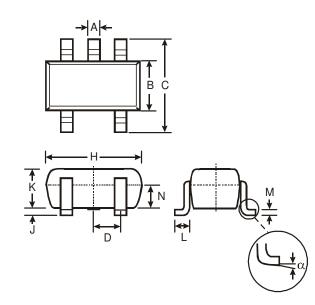
Part Number	Package	Identification Code
74AHC1G04W5	SOT25	ΥT
74AHC1G04SE	SOT353	ΥT



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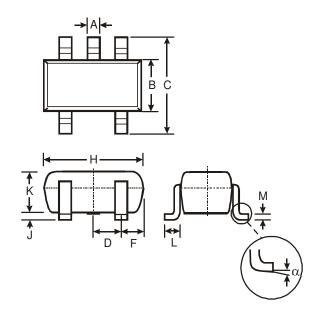
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



	SOT25							
Dim	Min	Max	Тур					
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D			0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
Κ	1.00	1.30	1.10					
L	0.35	0.55	0.40					
М	0.10	0.20	0.15					
Ν	0.70	0.80	0.75					
α	0°	8°	_					
All C)imensi	ons in	mm					

(2) Package Type: SOT353



SOT353							
Dim	Min	Max					
Α	0.10	0.30					
В	1.15	1.35					
С	2.00	2.20					
D	0.65	Тур					
F	0.40	0.45					
Н	1.80	2.20					
J	0	0.10					
К	0.90	1.00					
L	0.25	0.40					
М	0.10	0.22					
α	0°	8°					
All Di	mensions	in mm					



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